

INTERNATIONAL SEARCH REPORT

International application No.

PCT/SE 03/01309

A. CLASSIFICATION OF SUBJECT MATTER

IPC7: C30B 29/36, H01L 29/12

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

IPC7: H01L, C30B

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

SE,DK,FI,NO classes as above

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

EPO-INTERNAL, WPI DATA, INSPEC

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	Akira Itoh et al Chrystal Reviews in Solid State and Materials Sciences, 22(2):111-197 Singel Crystal Growth of SIC and Electronic Devices see whole document --	1-31
A	US 6030661 A (OLLE KORDINA ET AL), 29 February 2000 (29.02.00) --	1-31
A	J.R. Jenny et al Optical and electrical characterization of boron impurities in silicon carbide grown by physical vapor transport J. Appl. Phys 79 (5) 1 march 1996 --	1-31

☒ Further documents are listed in the continuation of Box C.

☒ See patent family annex.

* Special categories of cited documents

"A" document defining the general state of the art which is not considered to be of particular relevance

"E" earlier application or patent but published on or after the international filing date

"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)

"O" document referring to an oral disclosure, use, exhibition or other means

"P" document published prior to the international filing date but later than the priority date claimed

"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance: the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

"Y" document of particular relevance: the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art

"&" document member of the same patent family

Date of the actual completion of the international search

3 November 2003

Date of mailing of the international search report

07 -11- 2003

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C (Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	<p>M. Trivedi et al Dept. of Elec. Engg. & Comp.Sci University of Illinois at Chicaga IEEE 1998 Hight Temperature Performance Limits of IGBT Modules</p> <p style="text-align: center;">-- -----</p>	1-31

Form PCT/ISA/210 (continuation of second sheet) (July 1998)

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INTERNATIONAL SEARCH REPORT

Information on patent family members

06/09/03

International application No.

PCT/SE 03/01309

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
US 6030661 A	29/02/00	NONE	